NSN 5962-01-293-2286

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-293-2286 **Body Length:** Between 1.040 inches and 1.500 inches **Body Width:** Between 0.480 inches and 0.630 inches **Body Height:** Between 0.070 inches and 0.350 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** W/enable and electrostatic sensitive and programmable and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 13 input **Terminal Surface Treatment:** Solder

Voltage Rating And Type Per Characteristic:

5.0 volts power source

Time Rating Per Chacteristic:

300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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